

60mW, Capfree, Stereo Headphone Amplifier

The ISL99202 is a stereo, capfree headphone amplifier. The wide operating voltage of 2.4V to 5.5V makes it versatile enough to be used in mobile battery powered applications powered by 2 AA or Single cell Li-Ion batteries as well as 3.3/5V power supply available notebook computers.

The ISL99202 has robust RF immunity, which makes it ideally suited for today's mobile applications.

It has audiophile quality SNR and THD specifications and Click/Pop suppression.

The ISL99202 comes with Comprehensive Protection features, which include undervoltage and short-circuit protection and thermal shutdown.

The ISL99202 lowest power consumption in the industry is achieved by low I_{qq} and current shutdown.

The product is available in 12 Ld TQFN and 0.4mm pitch 12 ball WLCSP.

Features

- Supports 16Ω to 600Ω Speaker Impedance
- Ground Referenced: No Output Coupling Capacitors
- Audiophile Quality Sound THD of 0.01%, SNR of 102dB
- PSRR < -90dB, No Need for LDO
- Wide Operating Voltage of 2.4V to 5.5V
- < 3mA Quiescent Current and 0.1μA Shutdown Current
- State of the Art Pop and Click Suppression
- Pb-Free (RoHS Compliant)

Applications

- Mobile Phones
- MP3 Players

Ordering Information

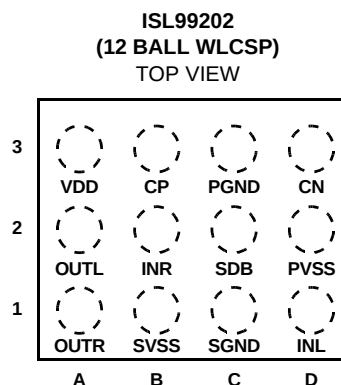
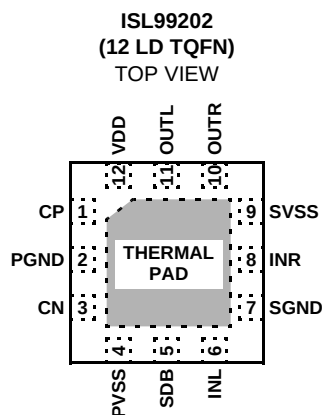
PART NUMBER	PART MARKING	GAIN SETTING (dB)	TEMP. RANGE (°C)	PACKAGE (Pb-Free)	PKG. DWG. #
ISL99202IIAZ-T* (Notes 1, 3)	202A	-1.5V/V	-40 to +85	12 Ball 3x4 WLCSP Array	W3x4.12
ISL99202IIBZ-T* (Notes 1, 3)	202B	Adjustable	-40 to +85	12 Ball 3x4 WLCSP Array	W3x4.12
ISL99202IRTAZ (Notes 2, 3)	202A	-1.5V/V	-40 to +85	12 Ld TQFN	L12.3x3Z
ISL99202IRTAZ-T* (Notes 2, 3)	202A	-1.5V/V	-40 to +85	12 Ld TQFN	L12.3x3Z
ISL99202IRTAZ-TK* (Notes 2, 3)	202A	-1.5V/V	-40 to +85	12 Ld TQFN	L12.3x3Z
ISL99202IRTBZ (Notes 2, 3)	202B	Adjustable	-40 to +85	12 Ld TQFN	L12.3x3Z
ISL99202IRTBZ-T* (Notes 2, 3)	202B	Adjustable	-40 to +85	12 Ld TQFN	L12.3x3Z
ISL99202IRTBZ-TK* (Notes 2, 3)	202B	Adjustable	-40 to +85	12 Ld TQFN	L12.3x3Z

*Please refer to TB347 for details on reel specifications.

NOTES:

1. These Intersil Pb-free WLCSP and BGA packaged products employ special Pb-free material sets; molding compounds/die attach materials and SnAgCu - e1 solder ball terminals, which are RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free WLCSP and BGA packaged products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
2. These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
3. Contact factory for ordering details.

Pinouts



Pin Descriptions

PIN NUMBER		PIN NAME	DESCRIPTION
TQFN	WLCSP		
1	B3	CP	Charge pump positive terminal
2	C3	PGND	Charge pump Ground
3	D3	CN	Charge pump negative terminal
4	D2	PVSS	Charge pump output
5	C2	SDB	Active low shutdown input
6	D1	INL	Left channel input
7	C1	SGND	Analog ground
8	B2	INR	Right channel input
9	B1	SVSS	Amplifier negative supply
10	A1	OUTR	Right channel output
11	A2	OUTL	Left channel output
12	A3	VDD	Positive power supply

NOTE: Exposed Pad is connected to PGND and SGND

Absolute Maximum Ratings (Reference to GND)

Supply Voltage	-0.3V to 6V
INR, INL, CP, SDB	-0.3V to $V_{DD} + 0.3V$
ESD Rating	
Human Body Model	
All pins	2kV
OUTL, OUTR	8kV
Machine Model	200V

Operating Conditions

Ambient Temperature Range	-40°C to +85°C
Maximum Supply Voltage (VDD Pin)	5.5V
Operating Supply Voltage (VDD Pin)	2.4V to 5V

Thermal Information

Thermal Resistance (Typical, Notes 4, 5)	θ_{JA} (°C/W)	θ_{JC} (°C/W)
TQFN Package	54	8
WLCSP Package	90	N/A
Maximum Junction Temperature (Plastic Package)	-65°C to +150°C	
Maximum Storage Temperature Range	-65°C to +150°C	
Dissipation Ratings		
Derating Factor		
12 LD 3x3 TQFN	14.7mW/°C	
12 Ball 3x4 Array WLCSP	10.1mW/°C	
Power Rating T_A		
12 Ld 3x3 TQFN		
+25°C	1.84W	
+70°C	1.12W	
+85°C	0.96W	
12 Ball 3x4 Array WLCSP		
+25°C	0.79W	
+70°C	0.33W	
+85°C	0.18W	
Pb-Free Reflow Profile	see link below	
	http://www.intersil.com/pbfree/Pb-FreeReflow.asp	

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

NOTES:

- θ_{JA} is measured in free air with the component mounted on a high effective thermal conductivity test board with "direct attach" features. See Tech Brief TB379.
- For θ_{JC} the "case temp." location is the center of the exposed metal pad on the package underside.

Electrical Specifications Typical Values are Tested at $V_{DD} = 5V$, $T_A = +25^\circ C$ and $R_L = 32\Omega$. All Maximum and Minimum Values are Established Under the Recommended Operating Supply Voltage Range and +25°C, Unless Otherwise Noted.

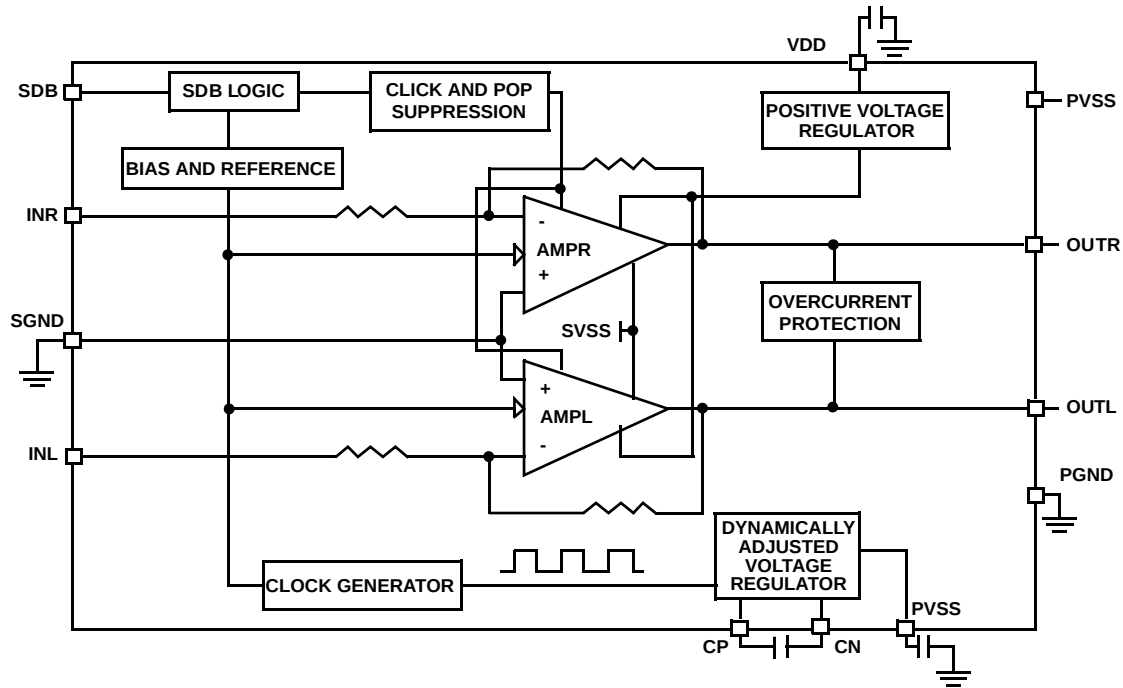
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
OUTPUT POWER						
Output Power (QFN)	P _{OUT}	R _L = 32Ω, THD = 1%	30	63		mW
		R _L = 16Ω		70		mW
Output Power (CSP)	P _{OUT}	R _L =32Ω	25	63		mW
		R _L =16Ω		70		mW
Total Harmonic Distortion + Ratio	THD+N	R _L = 1kΩ, V _{OUT} = 1.5V _{RMS} , f = 1kHz		0.003		%
		R _L = 32Ω, P _{OUT} = 50mW, f = 1kHz		0.01		%
		R _L = 16Ω, P _{OUT} = 35mW, f = 1kHz		0.02		%
PROTECTION						
Thermal Shutdown	OTP			160		°C
Thermal Shutdown Hysteresis				15		°C
Overcurrent Protection	OCP			200		mA
Undervoltage Shutdown					2.4	V
LOGIC INPUTS (SDB)						
Input Voltage High	V _{INH}		1.4			V
Input Voltage Low	V _{INL}				0.9	V
POWER SUPPLY						
Supply Voltage Range	V _{DD}		2.4		5.5	V

Electrical Specifications

Typical Values are Tested at $V_{DD} = 5V$, $T_A = +25^{\circ}C$ and $R_L = 32\Omega$. All Maximum and Minimum Values are Established Under the Recommended Operating Supply Voltage Range and $+25^{\circ}C$, Unless Otherwise Noted.
(Continued)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Power Supply Rejection Ratio	PSRR	V _{DD} = 2.5V to 5.0V at 217Hz		96		dB
		V _{DD} = 2.5V to 5.0V at 1kHz		88		dB
		V _{DD} = 2.5V to 5.0V at 20kHz		76		dB
Quiescent Current	I _{qq}	V _{DD} = 5.0V		3	4.6	mA
Shutdown Current	I _{SDB}	SDB = GND , V _{DD} = 5.0V		0.1	1.1	μA
GAIN CONTROL						
Voltage Gain	A _V		-1.55	-1.50	-1.45	V/V
Ch to Ch Gain Tracking				±0.15		%
Total Harmonic Distortion + Ratio	THD+N	R _L = 1kΩ, V _{OUT} = 1.5V _{RMS} , f = 1kHz		0.005		%
		R _L = 32Ω, P _{OUT} = 50mW, f = 1kHz		0.01		%
		R _L = 16Ω, P _{OUT} = 35mW, f = 1kHz		0.04		%
NOISE PERFORMANCE						
Signal to Noise Ratio	SNR	R _L = 1kΩ, V _{OUT} = 1.5V _{RMS} , BW = 22Hz to 20kHz		102		dB
		R _L = 1kΩ, V _{OUT} = 1.5V _{RMS} , BW = 22Hz to 20kHz, A-weighted		105		dB
		R _L = 32Ω, P _{OUT} = 35mW, BW = 22Hz to 20kHz		100		dB
		R _L = 32Ω, P _{OUT} = 35mW, BW = 22Hz to 20kHz, A-weighted		113		dB
Slew Rate	SR			0.5		VμS
Capacitive Drive	C _L			100		pF
Crosstalk (QFN, CSP)	xtalk	R _L = 16Ω, P _{OUT} = 15mW, f = 10kHz		-76		dB
Charge Pump Oscillation Frequency	f _{soc}		400	500	600	kHz
Click and Pop Level	K _{CP}	R _L = 32Ω, Peak voltage, Awtg. 32 sam/sec		-67		dB
V _{DD} = 3.0V						
Power Supply Rejection Ratio	PSRR	217Hz		96		dB
		1kHz		88		dB
		20kHz		76		dB
Quiescent Current	I _{qq}			2.4	3.6	mA
Shutdown Current	I _{SDB}	SDB = GND		0.1	1.1	μA
Output Offset Voltage	VOS		-1	0.05	1	mV
Output Power at 32Ω Load		R _L = 32Ω, THD = 1%		54		mW
Output Power at 16Ω Load		R _L = 16Ω, THD = 1%		56		mW
Total Harmonic Distortion + Noise Ratio	THD+N	R _L = 1kΩ, V _{OUT} = 1.5V _{RMS} , f = 1kHz		0.005		%
		R _L = 32Ω, P _{OUT} = 50mW, f = 1kHz		0.01		%
		R _L = 16Ω, P _{OUT} = 35mW, f = 1kHz		0.02		%

Block Diagram



Typical Performance Curves

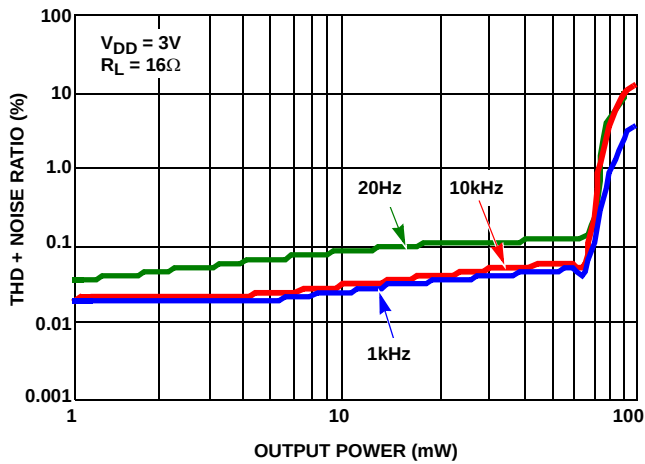


FIGURE 1. TOTAL HARMONIC DISTORTION + NOISE RATIO vs OUTPUT POWER

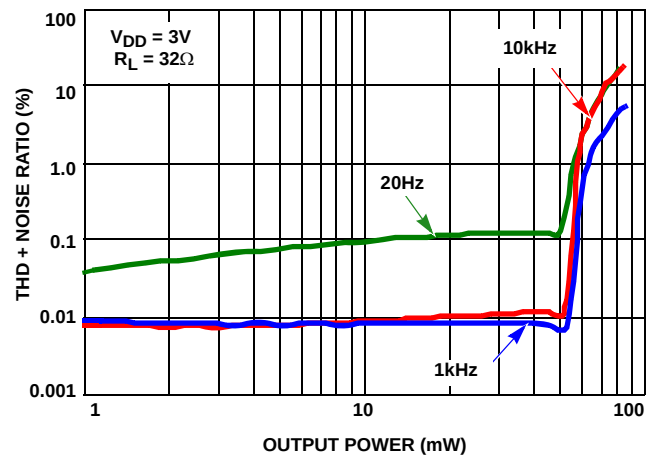


FIGURE 2. TOTAL HARMONIC DISTORTION + NOISE RATIO vs OUTPUT POWER

Typical Performance Curves (Continued)

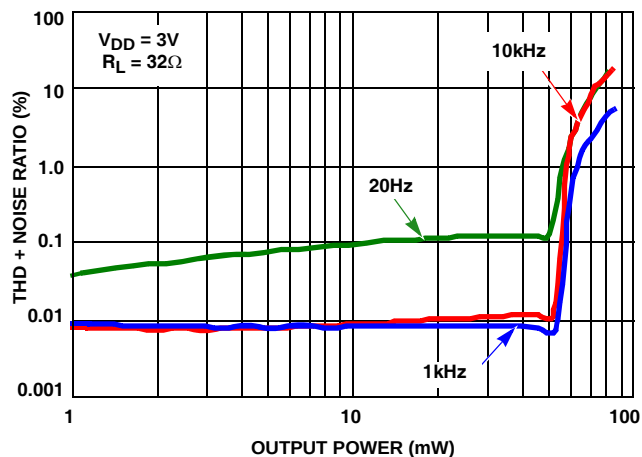


FIGURE 3. TOTAL HARMONIC DISTORTION + NOISE RATIO vs OUTPUT POWER

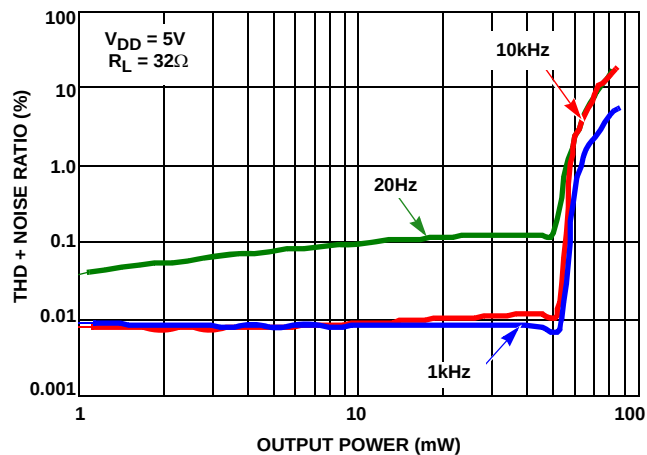


FIGURE 4. TOTAL HARMONIC DISTORTION + NOISE RATIO vs OUTPUT POWER

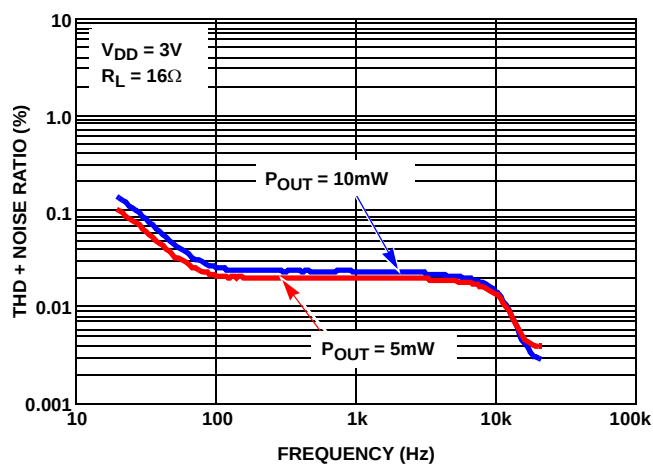


FIGURE 5. TOTAL HARMONIC DISTORTION + NOISE RATIO vs FREQUENCY

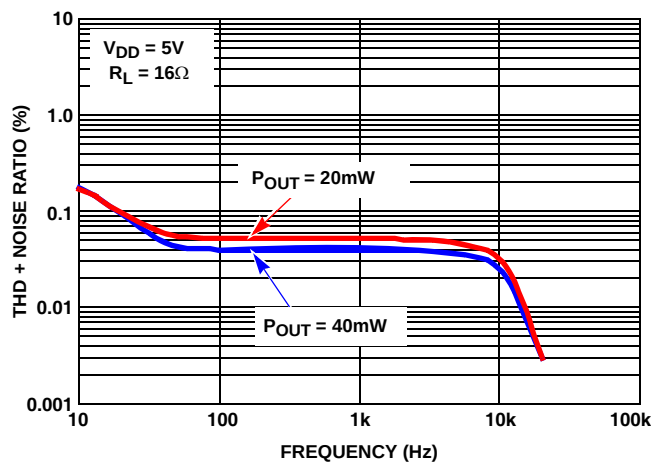


FIGURE 6. TOTAL HARMONIC DISTORTION + NOISE RATIO vs FREQUENCY

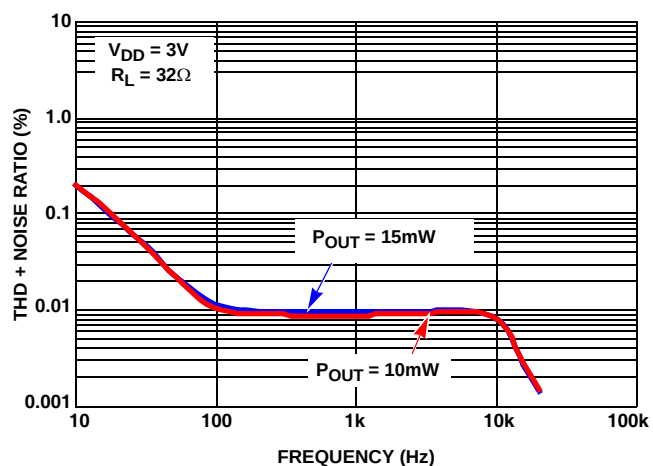


FIGURE 7. TOTAL HARMONIC DISTORTION + NOISE RATIO vs FREQUENCY

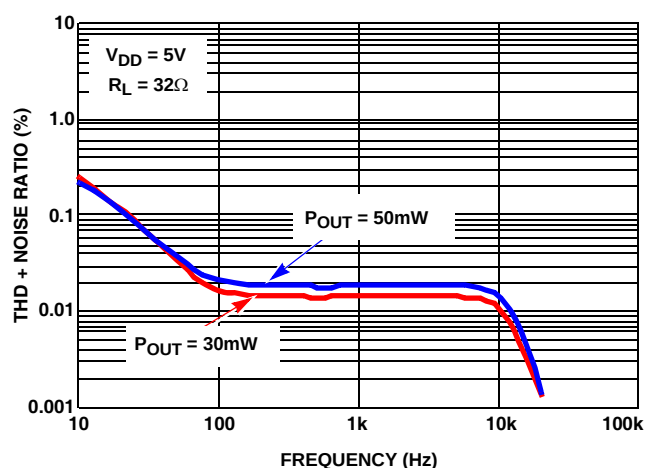


FIGURE 8. TOTAL HARMONIC DISTORTION + NOISE RATIO vs FREQUENCY

Typical Performance Curves (Continued)

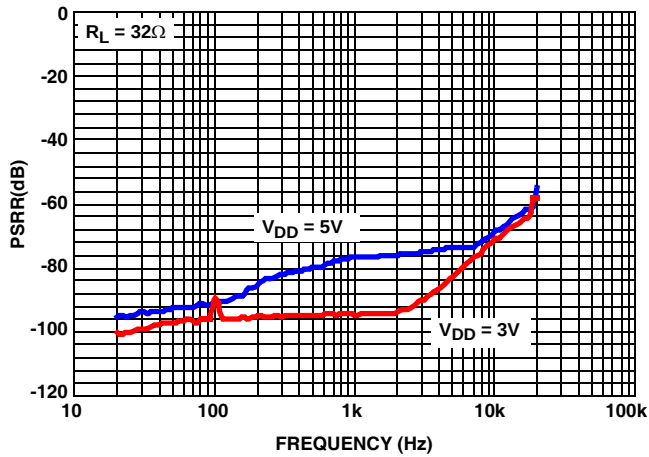


FIGURE 9. POWER SUPPLY REJECTION RATIO vs FREQUENCY

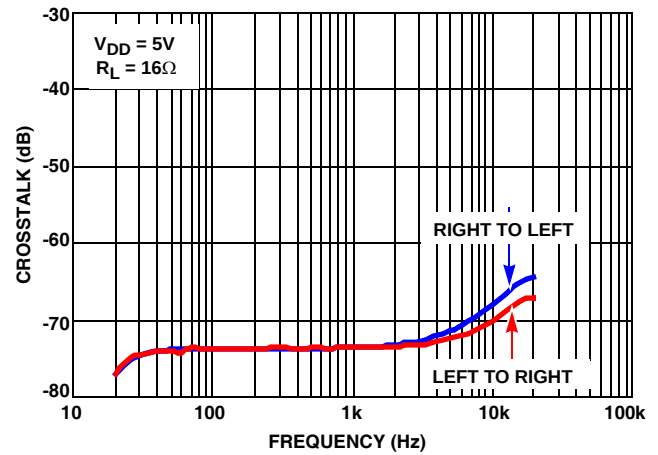


FIGURE 10. CROSSTALK vs FREQUENCY

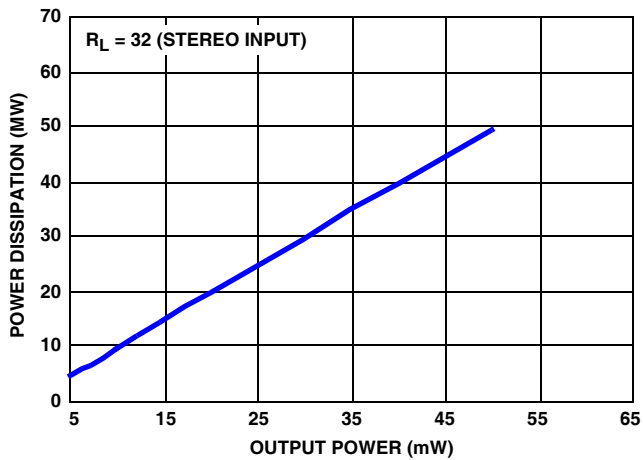


FIGURE 11. POWER DISSIPATION vs OUTPUT POWER

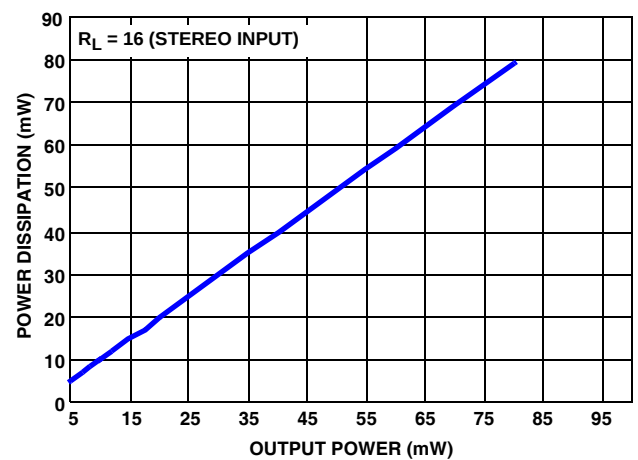


FIGURE 12. POWER DISSIPATION vs OUTPUT POWER

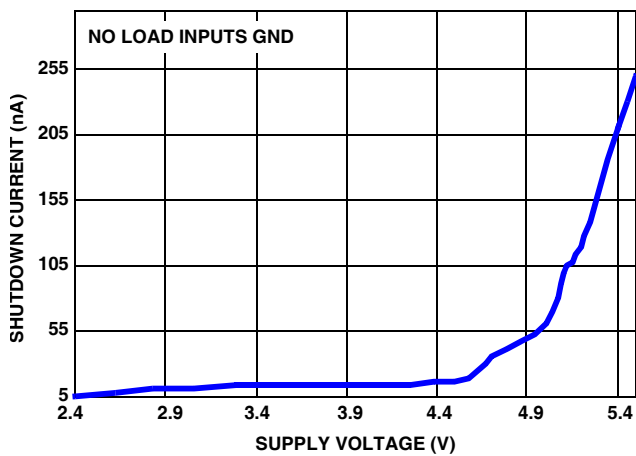


FIGURE 13. SHUTDOWN CURRENT vs SUPPLY VOLTAGE

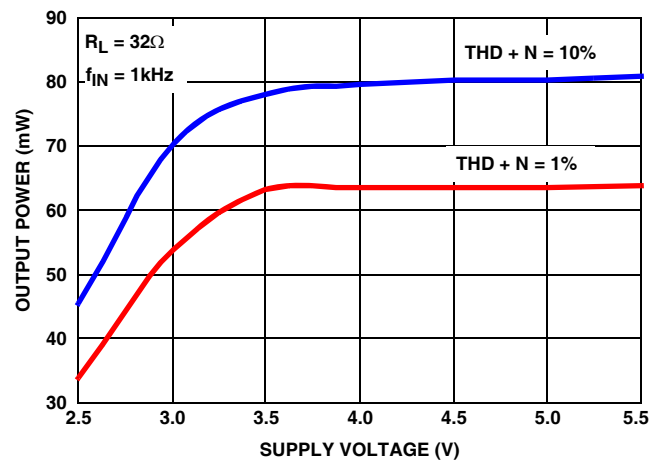


FIGURE 14. OUTPUT POWER vs SUPPLY VOLTAGE

Typical Performance Curves (Continued)

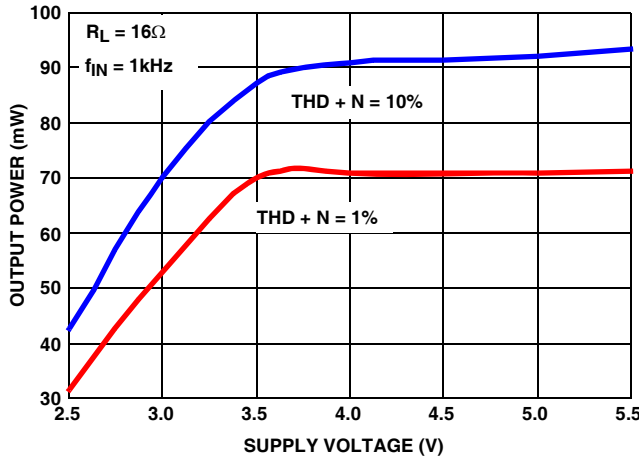


FIGURE 15. OUTPUT POWER vs SUPPLY VOLTAGE

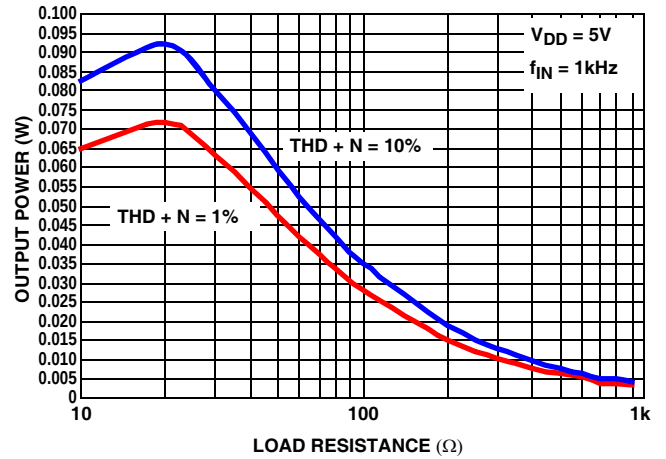


FIGURE 16. OUTPUT POWER vs LOAD RESISTANCE

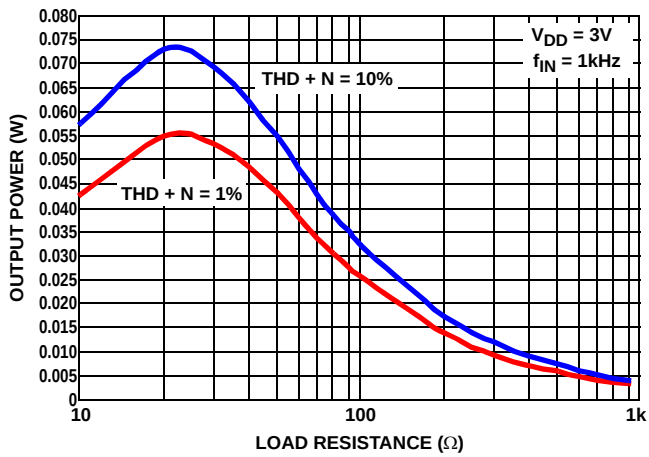


FIGURE 17. OUTPUT POWER vs. LOAD RESISTANCE

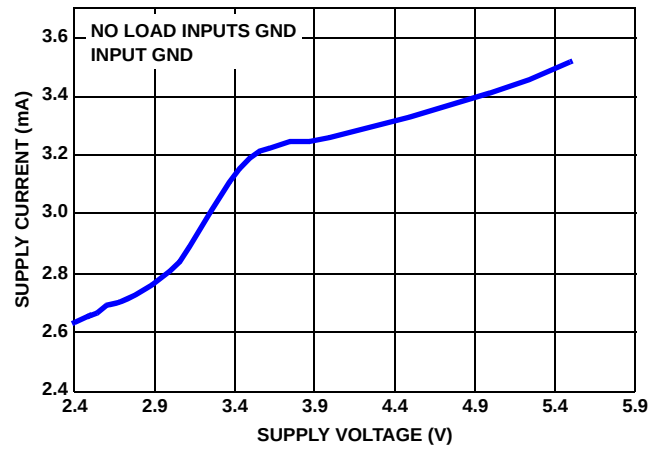


FIGURE 18. SUPPLY CURRENT vs. SUPPLY VOLTAGE

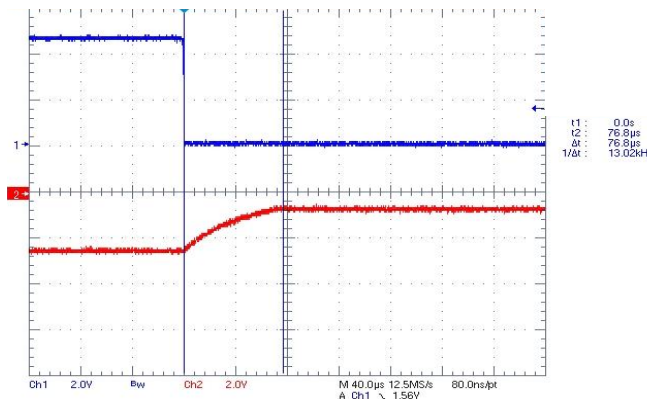


FIGURE 19. CHARGE PUMP RESPONSE FOR SDB GOING HIGH

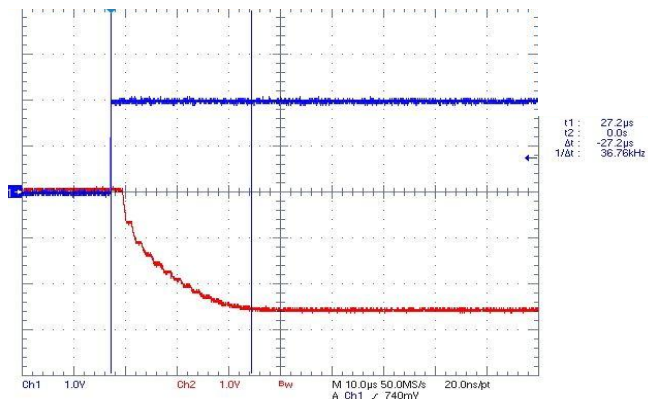
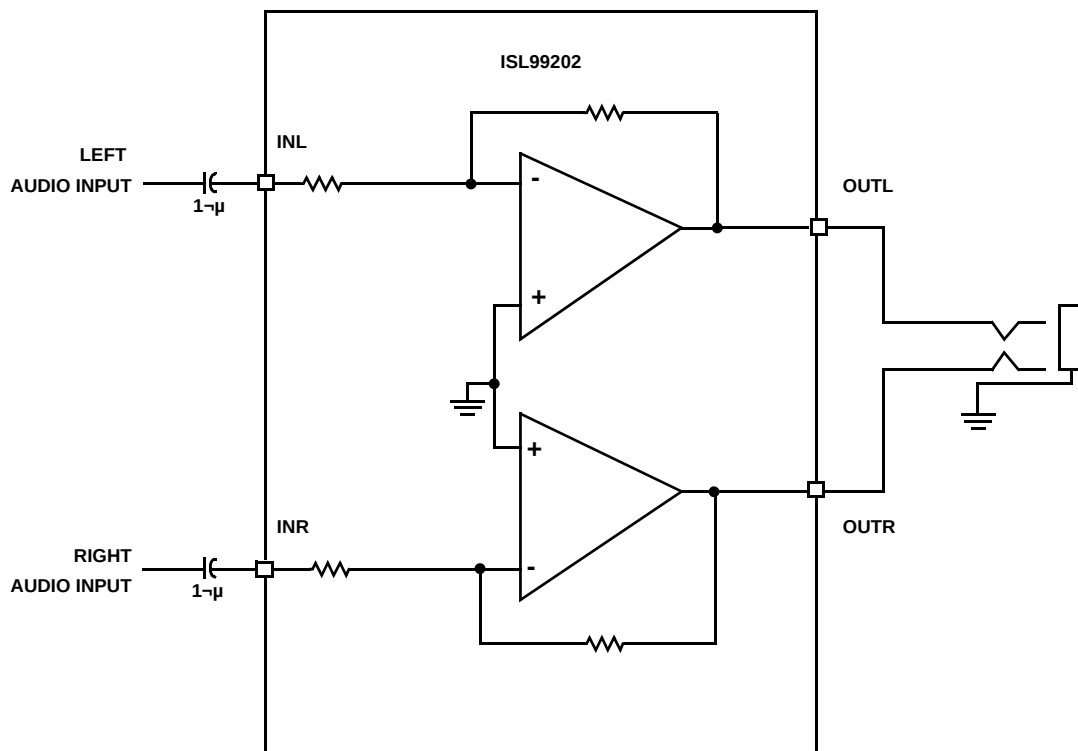


FIGURE 20. CHARGE PUMP RESPONSE FOR SDB GOING LOW

Typical Application Circuit



Detailed Description

The ISL99202 incorporates a novel proprietary architecture to eliminate the large output capacitors associated with single supply headphone amplifiers. Traditional charge pump based architectures that eliminated the output capacitors required additional power to operate the charge pump, which made them ill-suited for portable battery powered applications. The ISL99202 architecture eliminates the need for large output capacitors while consuming industry's lowest quiescent and shutdown currents.

Capfree Architecture

At the core of the Capfree architecture is a dynamically adjusted negative voltage regulator. By continuously monitoring the output power requirements, it adjusts the energy delivery circuitry. The feedback system ensures that overhead power required to deliver audio at the headphone speaker is always optimized for lower power dissipation.

Integrated LDO

A high precision LDO integrated into the power path of the amplifier accounts for a 92dB PSRR. This eliminates the need for a dedicated LDO used in some systems resulting in BOM/cost savings.

Offset Cancellation Circuitry

The DC offset is a very important parameter. It is a principal contributor to Click and Pop. In the cast Capfree architecture, the DC offset can also be a source of DC

current in quiescent state. The ISL99202 is tested and trimmed to have very low offset voltages (typically 50μV).

RF Immunity

Most portable applications for ISL99202 are subject to RF radiation from a myriad of sources, like Wi-Fi networks or cellular phone networks. Though these signals are not in the audio band, they can interfere with the audio signals through complex non-linear mechanisms, aliasing or demodulations to create audio band noise. The ISL99202 architecture prevents this coupling into audio band to achieve superior audio performance.

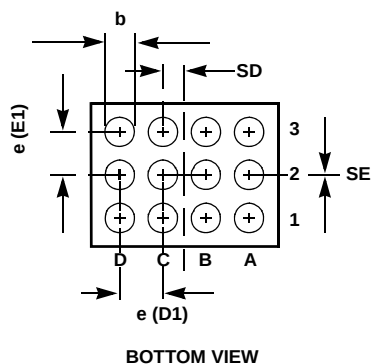
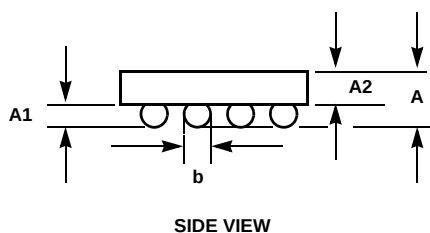
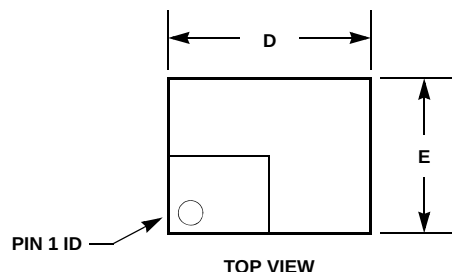
Protection Circuitry

The ISL99202 has comprehensive protection circuitry, which protects the part due to undervoltage, over-temperature and overcurrent. There is hysteresis built into over-temperature and undervoltage, while the overcurrent is designed to limit the output current in case of accidental short circuit or low impedance headphone load connection.

References

Intersil Technical Brief 451: "PCB Assembly Guidelines for Intersil Wafer Level Chip Scale Package Devices"
<http://www.intersil.com/data/tb/TB451.pdf>

Intersil Technical Brief 389: "PCB Land Pattern Design and Surface Mount Guidelines for QFN Packages"
<http://www.intersil.com/data/tb/tb389.pdf>

Wafer Level Chip Scale Package (WLCSP 0.4mm Ball Pitch)**W3x4.12****3x4 ARRAY 12 BALL WAFER LEVEL CHIP SCALE PACKAGE**

SYMBOL	MILLIMETERS
A	0.445 Min 0.495 Nom 0.545 Max
A1	0.190 ±0.025
A2	0.305 ±0.025
b	0.270 ±0.030
D	1.695 ±0.020
D1	0.400 BASIC
E	1.295 ±0.020
E1	0.400 BASIC
e	0.400 BASIC
SD	0.200 BASIC
SE	0 BASIC
NUMBER OF BUMPS: 12	

Rev. 0 12/08

NOTES:

1. All Dimensions are in Millimeters.

All Intersil U.S. products are manufactured, assembled and tested utilizing ISO9000 quality systems.

Intersil Corporation's quality certifications can be viewed at www.intersil.com/design/quality

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